40MHz to 500MHz VGA and I/Q Demodulator with 17MHz Baseband Bandwidth

FEATURES

- **17MHz I/Q Lowpass Output Noise Filters**
- **Wide Range 1.8V to 5.25V Supply Voltage**
- **Frequency Range: 40MHz to 500MHz**
- **THD < 0.14% (–57dBc) at 800mV$_{P-P}$ Differential Output Level**
- **IF Overload Detector**
- **Log Linear Gain Control Range: –7dB to 56dB**
- **Baseband I/Q Amplitude Imbalance: 0.2dB**
- **Baseband I/Q Phase Imbalance: 0.6°**
- **7.8dB Noise Figure at Max Gain**
- Input IP3 at Low Gain: –1dBm
- Low Supply Current: 24mA
- Low Delay Shift Over Gain Control Range: 2ps/dB
- Outputs Biased Up While in Standby
- 16-Lead QFN 4mm × 4mm Package with Exposed Pad

APPLICATIONS

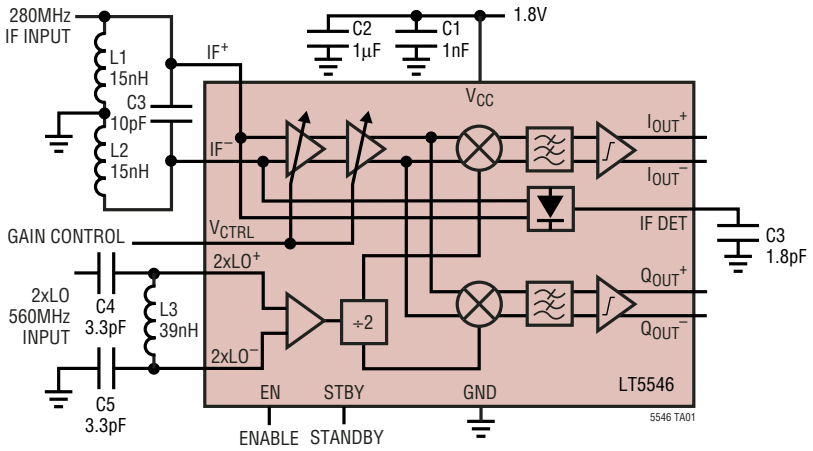
- GPS IF Receivers
- Satellite IF Receivers
- VHF/UHF Receivers
- Wireless Local Loop

DESCRIPTION

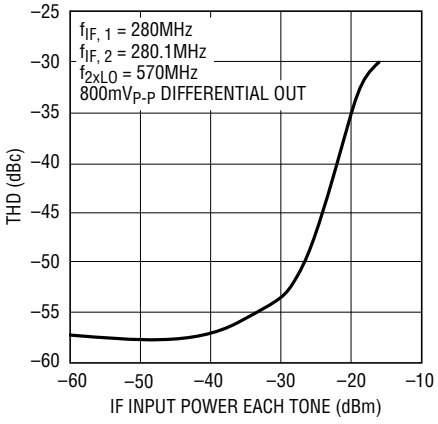
The LT®5546 is a 40MHz to 500MHz monolithic integrated quadrature demodulator with variable gain amplifier (VGA) and 17MHz I/Q baseband bandwidth designed for low voltage operation. It supports standards that use a linear modulation format. The chip consists of a VGA, quadrature downconverting mixers and 17MHz lowpass noise filters (LPF). The LO port consists of a divide-by-two stage and LO buffers. The IC provides all building blocks for IF downconversion to I and Q baseband signals with a single supply voltage of 1.8V to 5.25V. The VGA gain has a linear-in-dB relationship to the control input voltage. Hard-clipping amplifiers at the mixer outputs reduce the recovery time from a signal overload condition. The lowpass filters reduce the out-of-band noise and spurious frequency components. The –3dB corner frequency of the noise filters is approximately 17MHz and has a first order roll-off. The standby mode provides reduced supply current and fast transient response into the normal operating mode when the I/Q outputs are AC-coupled to a baseband chip.

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All other trademarks are the property of their respective owners.

TYPICAL APPLICATION



Total Harmonic Distortion vs IF Input Level at 1.8V Supply

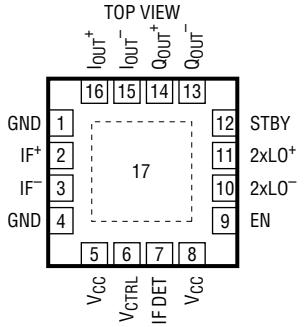


ABSOLUTE MAXIMUM RATINGS

(Note 1)

Supply Voltage 5.5V
Differential Voltage Between 2xLO$^+$ and 2xLO$^-$..... 4V
IF$^+$, IF$^-$ ..... –500mV to 500mV
I_{OUT}^+, I_{OUT}^-, Q_{OUT}^+, Q_{OUT}^-..... V_{CC} – 1.8V to V_{CC}
Operating Ambient Temperature
(Note 2) .....–40°C to 85°C
Storage Temperature Range .....–65°C to 125°C
Voltage on Any Pin
Not to Exceed ..... –500mV to V_{CC} + 500mV

PACKAGE/ORDER INFORMATION



UF PACKAGE
16-LEAD (4mm × 4mm) PLASTIC QFN
T_{JMAX} = 125°C, θ_{JA} = 37°C/W
EXPOSED PAD IS GND (PIN 17)
(MUST BE SOLDERED TO PCB)

ORDER PART NUMBER
LT5546EUF
UF PART MARKING
5546

Consult LTC Marketing for parts specified with wider operating temperature ranges.

ELECTRICAL CHARACTERISTICS

V_{CC} = 3V, f_{2xLO} = 570MHz, P_{2xLO} = –5dBm (Note 5), f_{IF} = 284MHz, P_{IF} = –30dBm, I and Q outputs 800mV$_{P-P}$ into 4kΩ differential load, T_A = 25°C, EN = V_{CC}, STBY = V_{CC}, unless otherwise noted. (Note 3)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
IF Input						
f_{IF}	Frequency Range			40 to 500		MHz
	Nominal Input Level	R_{SOURCE} = 200Ω Differential		–76 to –19		dBm
	Input Impedance	IF$^+$, IF$^-$ to GND, EN = V_{CC} IF$^+$, IF$^-$ to GND, EN = GND		100Ω//1.2pF 1pF		
NF	Noise Figure at Max Gain	V_{CTRL} = 1.7V		7.8		dB
G_L	Min Gain (Note 4)	V_{CTRL} = 0.2V		1.6	6	dB
G_H	Max Gain (Note 4)	V_{CTRL} = 1.7V	49	56		dB
IIP3	Input IP3, Min Gain Input IP3, Max Gain	P_{IF} = –22.5dBm (Note 7) P_{IF} = –75dBm (Note 7)		–1 –49		dBm dBm
IIP2	Input IP2, Min Gain Input IP2, Max Gain	V_{CTRL} = 0.2V (Note 9) V_{CTRL} = 1.7V (Note 9)		36 –25		dBm dBm
Demodulator I/Q Output						
	Nominal Voltage Swing	(Note 6)		0.8		V_{P-P}
	Clipping Level	(Note 6)		1.47		V_{P-P}
	DC Common Mode Voltage			V_{CC} – 1.19		V
	I/Q Amplitude Imbalance	(Note 8)		0.14	0.6	dB
	I/Q Phase Imbalance	(Note 8)		0.6	3	Deg
	DC Offset	(Notes 6, 8)		21		mV
	Output Driving Capability	Single Ended, $C_{LOAD} \leq$ 10pF	2	1.5		kΩ
r_o	Small-Signal Output Impedance	(Note 6)		180		Ω
	STBY to Turn-On Delay			0.3		µs
	I/Q Output 1dB Compression			–10		dBm
	I/Q Output IM3	$P_{IF,1}$ = –25.5dBm, 280MHz $P_{IF,2}$ = –25.5dBm, 280.1MHz (Note 7)		–49		dBc

ELECTRICAL CHARACTERISTICS

V_{CC} = 3V, f_{2xLO} = 570MHz, P_{2xLO} = –5dBm (Note 5), f_{IF} = 284MHz, P_{IF} = –30dBm, I and Q outputs 800mV$_{P-P}$ into 4kΩ differential load, T_A = 25°C, EN = V_{CC}, STBY = V_{CC}, unless otherwise noted. (Note 3)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Variable Gain Amplifier (VGA)						
	Gain Slope Linearity Error	V_{CTRL} = 0V to 1.4V		±0.5		dB
	Temperature Gain Shift	T = –40°C to 85°C, V_{CTRL} = 0V to 1.4V		±0.4		dB
	Gain Control Response Time	Settled within 10% of Final Value		90		ns
	Gain Control Voltage Range			0 to 1.7		V
	Gain Control Slope			41		dB/V
	Gain Control Input Impedance	To Internal 0.2V Reference		25		kΩ
	Delay Shift Over Gain Control	Measured Over 10dB Step		2		ps/dB
Baseband Lowpass Filter (LPF)						
	–3dB Cutoff Frequency		13	17		MHz
	Amplitude Roll-Off at 50MHz			–9		dB
	Group Delay Ripple			1		ns
2xLO Input						
f_{2xLO}	Frequency Range			80 to 1000		MHz
P_{2xLO}	Input Power	1:2 Transformer with 240Ω Shunt Resistor (Note 5)	–20	–5		dBm
	Input Power	LC Balun (Note 5)		–10		dBm
	Input Impedance	Differential Between 2xLO$^+$ and 2xLO$^-$		800Ω//0.4pF		
	DC Common Mode Voltage			V_{CC} – 0.4		V
IF Detector						
	IF Detector Range	Referred to IF Input		–30 to 8		dBm
	Output Voltage Range	For P_{IF} = –30dBm to 8dBm		0.27 to 1.2		V
	Detector Response Time	With External 1.8pF Load, Settling within 10% of Final Value		80		ns
Power Supply						
V_{CC}	Supply Voltage		1.8		5.25	V
I_{CC}	Supply Current	EN = High, STBY = Low or High		24	34	mA
I_{OFF}	Shutdown Current	EN, STBY < 350mV		0.2	30	µA
I_{STBY}	Standby Current	EN = Low; STBY = High		3.6	6	mA
Mode						
Enable	Enable Pin Voltage	EN = High	1			V
Disable	Enable Pin Voltage	EN = Low			0.5	V
Standby	Standby Pin Voltage	STBY = High	1			V
No Standby	Standby Pin Voltage	STBY = Low			0.5	V

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: Specifications over the –40°C to 85°C temperature range are assured by design, characterization and correlation with statistical process controls.

Note 3: Tests are performed as shown in the configuration of Figure 6. The IF input transformer loss is substracted from the measured values.

Note 4: Power gain is defined here as the I (or Q) output power into a 4kΩ differential load, divided by the IF input power in dB. To calculate the voltage gain between the differential I output (or Q output) and the IF input, including ideal matching network, 10 • log(4kΩ/50) = 19dB has to be added to this power gain.

Note 5: If a narrow-band match is used in the 2xLO path instead of a 1:2 transformer with 240Ω shunt resistor, 2xLO input power can be reduced to –10dBm, without degrading the phase imbalance. See Figure 11 and Figure 6.

Note 6: Differential between I_{OUT}^+ and I_{OUT}^- (or differential between Q_{OUT}^+ and Q_{OUT}^-).

Note 7: The gain control voltage V_{CTRL} is set in such a way that the differential output voltage between I_{OUT}^+ and I_{OUT}^- (or differential between Q_{OUT}^+ and Q_{OUT}^-) is 800mV$_{P-P}$, with the given input power P_{IF}. IF frequencies are 280MHz and 280.1MHz, with f_{2xLO} = 570MHz.

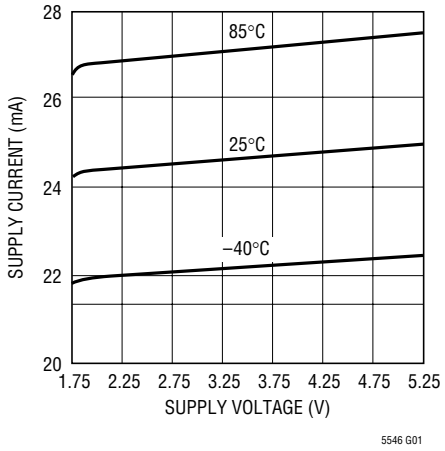
Note 8: The typical parameter is defined as the mean of the absolute values of the data distribution.

Note 9: IF frequency is 125MHz, with f_{2xLO} = 502MHz.

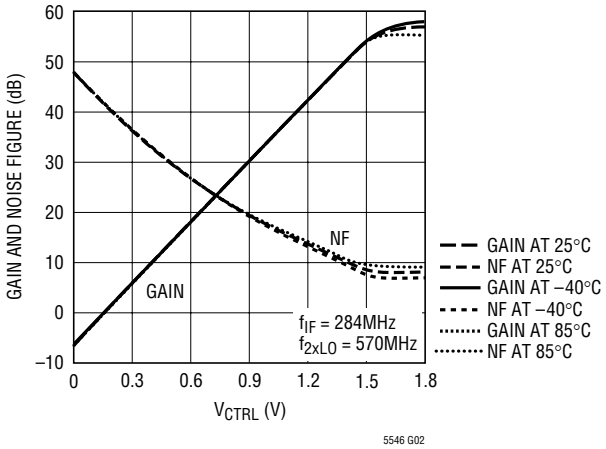
TYPICAL PERFORMANCE CHARACTERISTICS

V_{CC} = 3V, $f_{2\times LO}$ = 570MHz, $P_{2\times LO}$ = –5dBm (Note 5), f_{IF} = 284MHz, P_{IF} = –30dBm, I and Q outputs 800mV_{P-P} into 4kΩ differential load, T_A = 25°C, EN = V_{CC}, STBY = V_{CC}, unless otherwise noted. (Note 3)

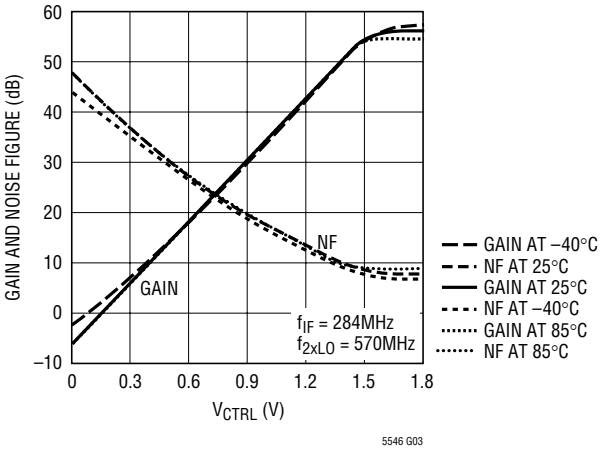
Supply Current vs Supply Voltage



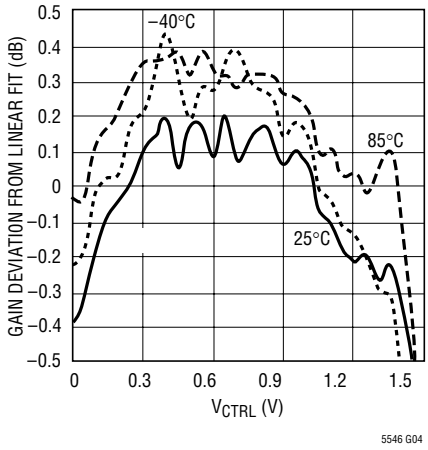
Gain and Noise Figure vs Control Voltage at 3V Supply



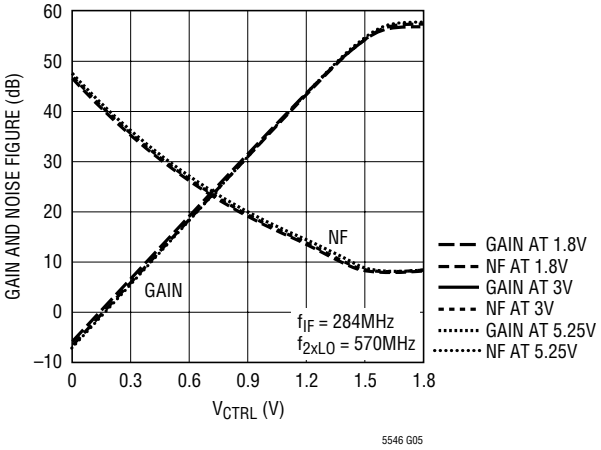
Gain and Noise Figure vs Control Voltage at 1.8V Supply



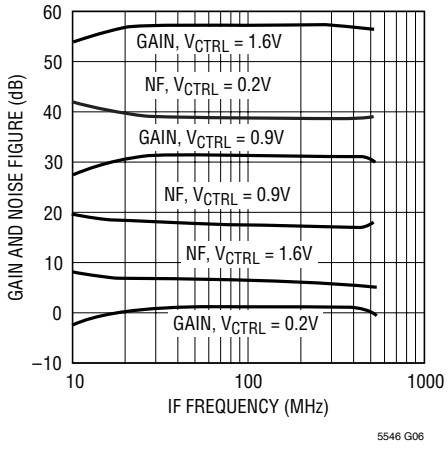
Gain Flatness vs Control Voltage at 3V Supply



Gain and Noise Figure vs Control Voltage and V_{CC}



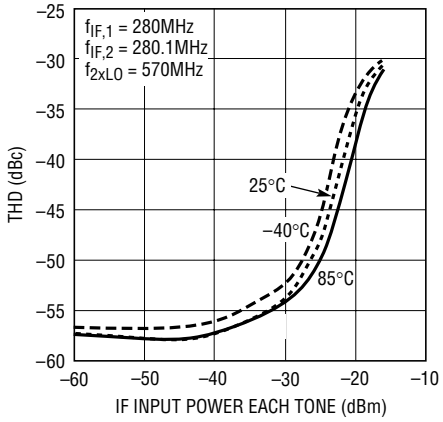
Gain and Noise Figure vs IF Frequency at 3V Supply



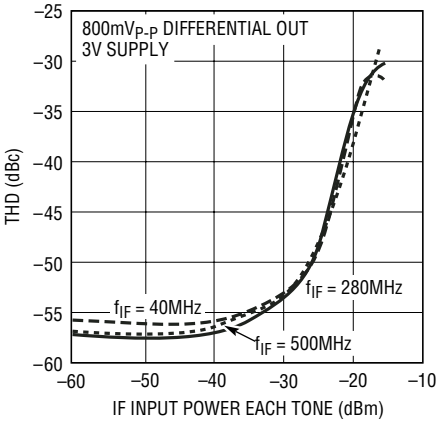
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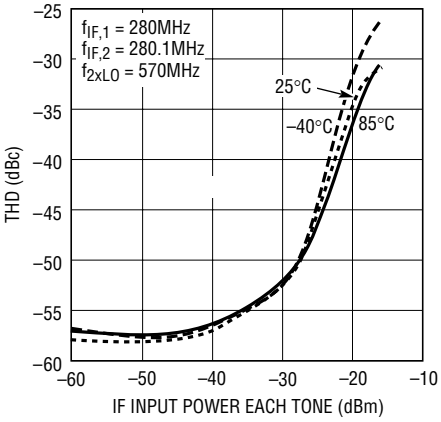
Total Harmonic Distortion vs IF Input Power at 3V Supply and 800mV$_{P-P}$ Differential Out



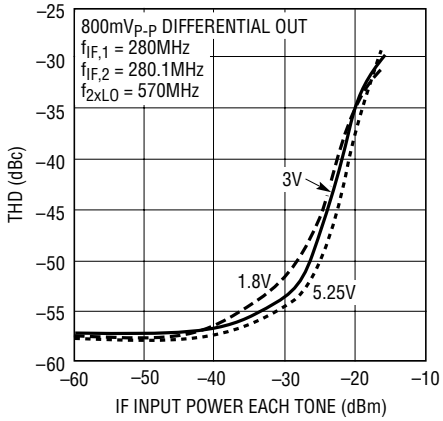
Total Harmonic Distortion vs IF Input Power and IF Frequency



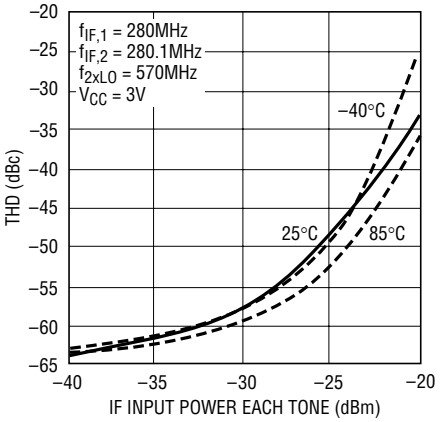
Total Harmonic Distortion vs IF Input Power at 1.8V Supply and 800mV$_{P-P}$ Differential Out



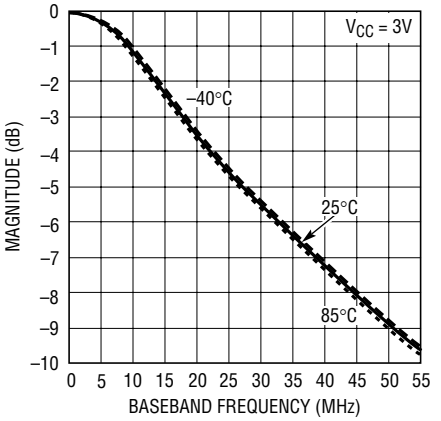
Total Harmonic Distortion vs IF Input Power and Supply Voltage



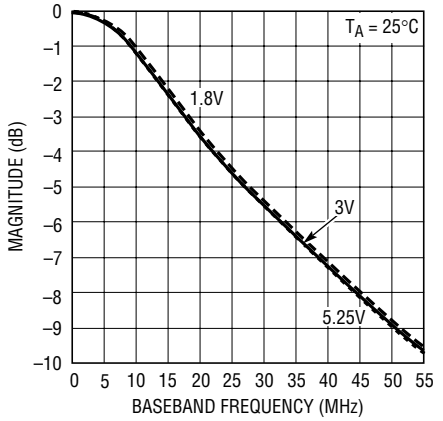
Total Harmonic Distortion vs IF Input Power at 500mV$_{P-P}$ Differential Out



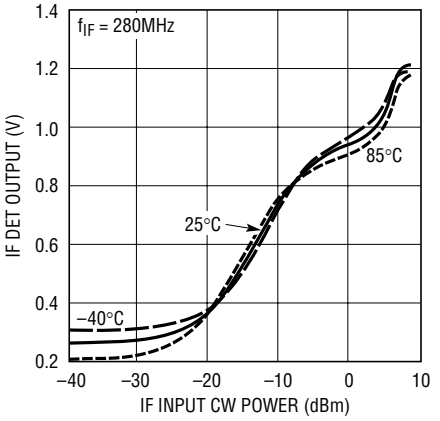
LPF Frequency Response vs Baseband Frequency and Temperature



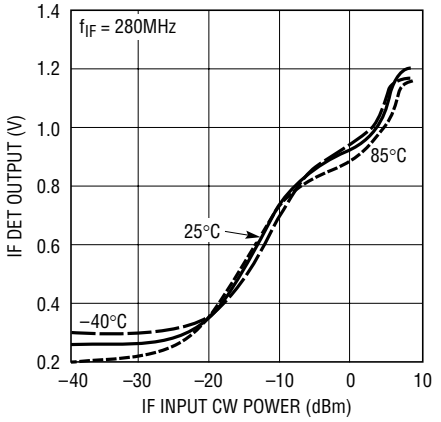
LPF Frequency Response vs Baseband Frequency and Supply Voltage



IF Detector Output Voltage vs IF Input CW Power at 3V Supply



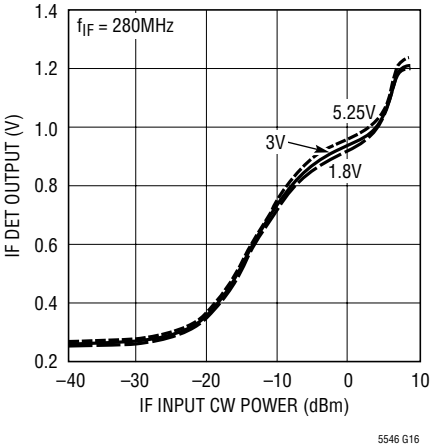
IF Detector Output Voltage vs IF Input CW Power at 1.8V Supply



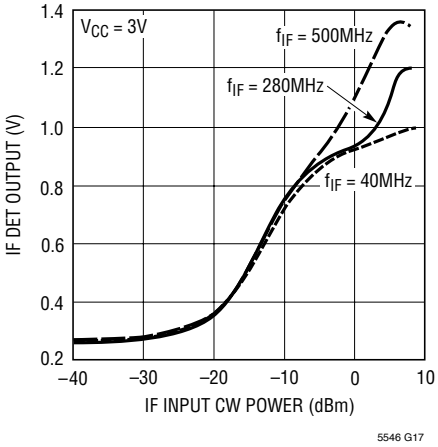
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V_{CC} = 3V, $f_{2×LO}$ = 570MHz, $P_{2×LO}$ = –5dBm (Note 5), f_{IF} = 284MHz, P_{IF} = –30dBm, I and Q outputs 800mV_{P-P} into 4kΩ differential load, T_A = 25°C, EN = V_{CC}, STBY = V_{CC}, unless otherwise noted. (Note 3)

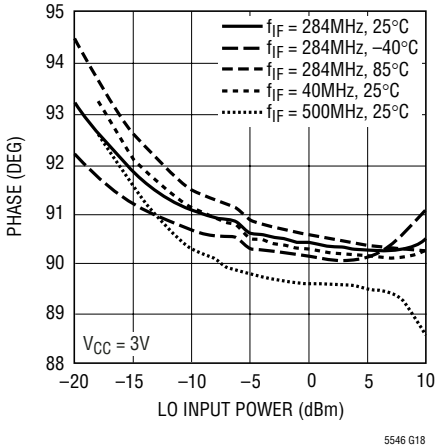
IF Detector Output Voltage vs IF Input CW Power and Supply Voltage



IF Detector Output Voltage vs IF Input CW Power and IF Frequency



Phase Relation Between I and Q Outputs vs LO Input Power



PIN FUNCTIONS

GND (Pins 1, 4 and 17): Ground. Pins 1 and 4 are connected to each other internally. The exposed pad (Pin 17) is not connected internally to Pins 1 and 4. For chip functionality, the exposed pad and either Pin 1 or Pin 4 must be connected to ground. For best RF performance, Pin 1, Pin 4 and the exposed pad should be connected to RF ground.

IF^+, $IF^–$ (Pins 2, 3): Differential Inputs for the IF Signal. Each pin must be DC grounded through an external inductor or RF transformer with central ground tap. This path should have a DC resistance lower than 2Ω to ground.

V_{CC} (Pins 5 and 8): Power Supply. These pins should be decoupled to ground using 1000pF and 0.1µF capacitors.

V_{CTRL} (Pin 6): VGA Gain Control Input. This pin controls the IF gain and its typical input voltage range is 0.2V to 1.7V. It is internally biased via a 25k resistor to 0.2V, setting a low gain if the V_{CTRL} pin is left floating.

IF DET (Pin 7): IF Detector Output. For strong IF input signals, the DC level at this pin is a function of the IF input signal level.

EN (Pin 9): Enable Input. When the enable pin voltage is higher than 1V, the IC is completely turned on. When the input voltage is less than 0.5V, the IC is turned off, except the part of the circuit associated with standby mode.

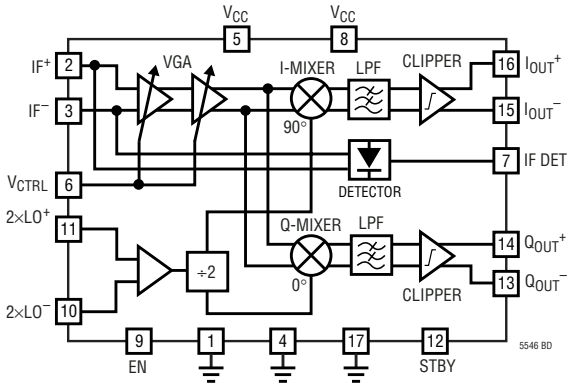
$2xLO^–$, $2xLO^+$ (Pins 10, 11): Differential Inputs for the 2xLO Input. The 2xLO input frequency must be twice that of the IF frequency. The internal bias voltage is V_{CC} – 0.4V.

STBY (Pin 12): Standby Input. When the STBY pin is higher than 1V, the standby mode circuit is turned on to prebias the I/Q buffers. When the STBY pin is less than 0.5V, the standby mode circuit is turned off.

$Q_{OUT}^–$, Q_{OUT}^+ (Pins 13, 14): Differential Baseband Outputs of the Q Channel. Internally biased at V_{CC} – 1.19V.

$I_{OUT}^–$, I_{OUT}^+ (Pins 15, 16): Differential Baseband Outputs of the I Channel. Internally biased at V_{CC} – 1.19V.

BLOCK DIAGRAM



APPLICATIONS INFORMATION

The LT5546 consists of a variable gain amplifier (VGA), I/Q demodulator, quadrature LO generator, lowpass filters (LPFs), clipping amplifiers (clippers) and bias circuitry.

The IF signal is fed to the inputs of the VGA. The VGA gain is typically set by an external signal in such a way that the amplified IF signal delivered to the I/Q mixers is constant. The IF signal is then converted into I/Q baseband signals using the I/Q down-converting mixers. The quadrature LO signals that drive the mixers are internally generated from the on-chip divide-by-two circuit. The I/Q signals are passed through first-order low-pass filters and subsequently a pair of hard-clipping amplifiers (clippers). After externally setting the required gain, these amplifiers should not clip. However, in the event of overload, they reduce the settling time of any (optional) external AC coupling capacitors by preventing asymmetrical charging and discharging effects. The I/Q baseband outputs are buffered by output drivers.

VGA and Input Matching

The VGA has a nominal 60dB gain control range with a frequency range of 40MHz to 500MHz. The inputs of the VGA must have a DC return to ground. This can be done using a transformer with a central tap (on the secondary) or an LC matching circuit with a matched impedance at the frequency of interest and near zero impedance at DC. The differential AC input impedance of the LT5546 is about 200Ω, thus a 1:4 (impedance ratio) RF transformer with center tap can be used. In Figure 6, the evaluation board schematic is shown using a 1:4 transformer. The measured input sensitivity of this board is about –80.5dBm for a 10dB signal-to-noise ratio. In the case of an L-C matching circuit, the circuit of Figure 1 can be used. In Table 1 the matching network component values are given for a range of IF frequencies. The matching circuit of Figure 1 approaches 180° phase shift between IF^+ and $IF^–$ in a broad range around its center frequency. However, some amplitude mismatch occurs if the circuit is not tuned to the center frequency. This leads to reduced circuit linearity performance, because one of the inputs carries a higher signal compared to the perfectly balanced case. A 10% frequency shift from the center frequency results in about a 2dB gain difference between the IF^+ and $IF^–$ inputs. This results in a 1.5dB higher IM3 contribution from the input stage which leads to a 0.75dB drop in IIP3. Moreover, the IIP2 of the circuit is also reduced which can lead to a higher second order harmonic contribution. The circuit can be driven single ended, but this is not recommended because it leads to a 3dB drop in gain and a considerable increase in IM5 and IM7 components. The single-ended noise figure increases by 4dB if one IF input is directly grounded and increases by 1.5dB if one IF input is grounded via a 1μH inductor. An IF input cannot be left open or connected via a resistor to ground because this will disturb the internal biasing, reducing the gain, noise and linearity performance. For optimal performance, it is important to keep the DC impedance to ground of both IF inputs lower than 2Ω. In the matching network of Figure 1, inductor L3 is used for supplying the DC bias current to the IF^+ input.

APPLICATIONS INFORMATION

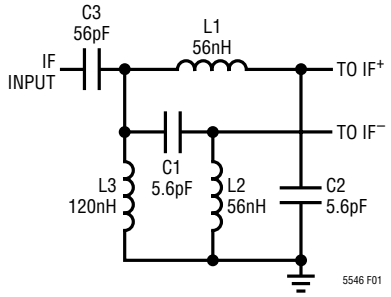


Figure 1. Example L-C IF Input Matching Network at 280MHz

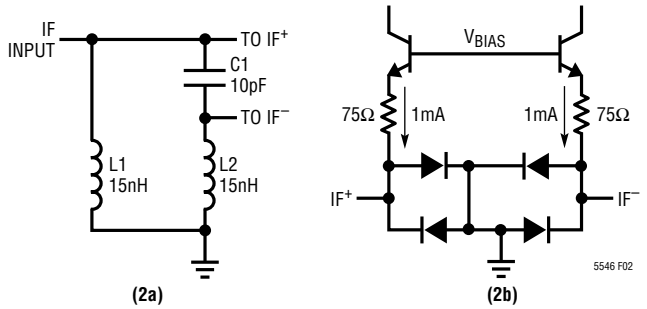


Figure 2a. Simplified IF Input Matching Network at 280MHz and Figure 2b. Simplified Circuit Schematic of the IF Inputs

Table 1. The Component Values of Matching Network L1, L2, L3, C1, C2 and C3.

f_{IF}(MHz)	L1, L2(nH)	C1, C2(pF)	L3(nH)	C3(pF)
50	340	34	1800	820
100	159	15.9	470	220
150	106	10.6	470	220
200	80	8.0	470	220
250	64	6.4	120	56
300	53	5.3	120	56
350	45	4.5	120	56
400	40	4.0	120	56
450	35	3.5	120	56
500	32	3.2	120	56

To keep the DC resistance of L3 below 2Ω, 120nH is used. This disturbs the matching network slightly by causing the frequency where the S11 is minimal to be lower than the frequency where the amplitudes of IF^+ and IF^- are equal. To compensate for this, the value of coupling capacitor C3 is lowered and will contribute some correcting reactance. For low frequencies, it might not be possible to find any practical inductor value for L3 with DC resistance smaller than 2Ω. In that case it is recommended to use a transformer with a center tap. The tolerance for the components in Figure 1 can be 10% for a return loss higher than 16dB and a gain reduction due to mismatch less than 0.3dB.

It is possible to simplify the input matching circuit and compromise the performance. In Figure 2a, the simplified matching network is given.

This matching network can deliver equal amplitudes to the IF^+ and IF^- inputs for a narrow frequency region, but the phase difference between the inputs will not be exactly 180 degrees. In practice, the phase shift will be around 145 degrees, depending on the quality factor of the network. This will result in a reduction in the gain. The higher the chosen quality factor, the closer the phase difference will approach 180 degrees. However, a higher quality factor will reduce bandwidth and create more loss in the matching network. For minimum board space, 0402 components are used. The measured noise figure for maximum gain with this matching network is about 9.4dB, and the maximum gain is about 55dB. Assuming 0402 inductors with Q = 35, the insertion loss of this network is about 2.5dB. The tolerance for the components in Figure 2a can be 10% for a return loss higher than 10dB and a gain reduction due to mismatch less than 0.5dB. The measured input sensitivity for this matching network (see also Figure 11) is about –78.3dBm for a 10dB signal-to-noise ratio.

The gain of the VGA is set by the voltage at the V_{CTRL} pin. For high gain settings, both the noise figure and the input IP3 will be low. From a noise figure point of view, it is advantageous to work as closely as possible to the maximum gain point. However, if the voltage at the V_{CTRL} pin is increased beyond the maximum gain point (where additional increase in control voltage does not give an increase in gain), the response time of the gain control circuit is increased. If control speed is crucial, a few dB of gain margin should be allowed from the highest gain point to be sure that at all temperatures, the maximum gain setting is not crossed. At low gain settings, the noise figure and the input IP3 will be high. Optionally, the control voltage V_{CTRL} can be set lower than 0.2V. The normal range is from V_{CTRL} = 0.2V to 1.7V, which results in a nominal gain range from 1.6dB to 56.8dB. The linear-in-dB gain relation with the V_{CTRL} voltage still holds for control voltages as low as –0.35V. This results in an

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extended gain control range of –23dB to 57dB. The V_{CTRL} pin is a very sensitive input because of its high input impedance and therefore should be well shielded. Signal pickup on the V_{CTRL} pin can lead to spurs and increased noise floor in the I/Q baseband outputs. It can degrade the linearity performance and it can cause asymmetry in the two-tone test. If control speed is not important, 1µF bypass capacitors are recommended between V_{CTRL} and ground.

A fast responding peak detector is connected to the VGA input, sensitive to signal levels above the signal levels where the VGA is operating in the linear range. It is active from –22dBm up to 5dBm IF input signal levels. The DC output voltage of this detector (IF DET) can be used by the baseband controller to quickly determine the presence of a strong input level at the desired channel, and adjust gain accordingly. Figure 3a shows the simplified circuit schematic of the IF DET output.

I/Q Demodulators

The quadrature demodulators are double balanced mixers, down-converting the amplified IF signal from the VGA into I/Q baseband signals. The quadrature LO signals are generated internally from a double frequency external CW signal. The nominal output voltage of the differential I/Q baseband signals should be set to $0.8V_{P-P}$ or lower, depending on the linearity requirements. The magnitudes of I and Q are well matched and their phases are 90° apart.

Quadrature LO Generator

The quadrature LO generator consists of a divide-by-two circuit and LO buffers. An input signal (2xLO) with twice the desired IF signal frequency is used as the clock for the divide-by-two circuit, producing the quadrature LO signals for the demodulators. The outputs are buffered and then drive the down-converting mixers. With a fully differential approach, the quadrature LO signals are well matched. Second harmonic content (or higher order even harmonics) in the external 2xLO signal can degrade the 90° phase shift between I and Q. Therefore, such content should be minimized. In disable or standby mode, the divide-by-two stage is powered down. After enabling the circuit, the phase relation between the IF signal and the baseband (I or Q) signals can be either 0° or 180°, since the circuit cannot distinguish between the two subsequent identical sinusoi-

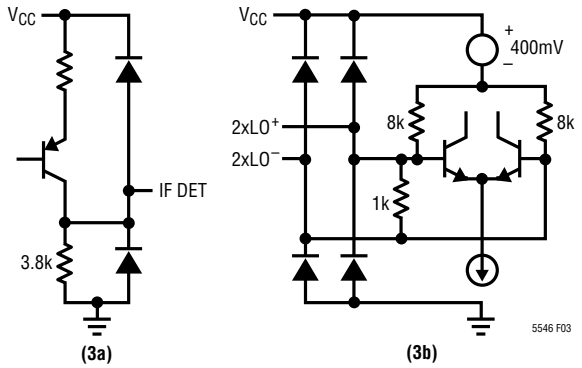


Figure 3a. Simplified Circuit Schematic of the IF DET Output and Figure 3b. The 2xLO Inputs

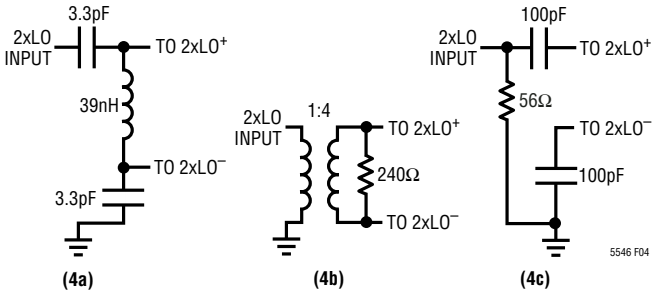


Figure 4. 2xLO Input Matching Networks for 4a) Narrow Band Tuned to 570MHz, 4b) Wide Band, 4c) Single-Ended Wide Band

dal waveforms of the 2xLO input signal. The phase relation between I and Q is always 90°, i.e. I always leads Q by 90° for $f_{IF} > 1/2 \bullet f_{2xLO}$. Figure 3b shows the simplified circuit schematic of the 2xLO inputs. Depending on the application, different 2xLO input matching networks can be chosen. In Figure 4, three examples are given. The first network provides the best 2xLO input sensitivity because it can boost the 2xLO differential input signal using a narrow-band resonant approach. The second network gives a wide-band match, but the 2xLO input sensitivity is about 2dB lower. The third network gives a simple and less expensive wide-band match, but 2xLO input sensitivity drops by about 9dB. The IF input sensitivity doesn't change significantly using any of the three 2xLO matching networks.

Baseband Circuit

The baseband circuit consists of I/Q low-pass filters, I/Q hard limiters (clippers) and I/Q output buffers. The hard limiters operate as linear amplifiers normally. However, if a high level input temporarily overloads a linear amplifier,

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then the circuit will limit symmetrically, which will help to prevent the output buffer from overloading. This speeds up recovery from an overload event, which can occur during the gain settling. The clipping level is approximately constant over temperature. The first order integrated lowpass filters are used for noise filtering of the down-converted baseband signals for both the I channel and the Q channel. These filters are well matched in gain response. The –3dB corner frequency is typically 17MHz. The I/Q outputs can drive 2kΩ in parallel with a maximum capacitive loading of 10pF at 5MHz, from all four pins to ground. The outputs are internally biased at V_{CC} – 1.19V. Figure 5 shows the simplified output circuit schematic of the I channel or Q channel.

The I/Q baseband outputs can be DC-coupled to the inputs of a baseband chip. For AC-coupled applications with large capacitors, the STBY pin can be used to pre-bias the outputs to nominal V_{CC} – 1.19V at much reduced current. This mode draws only 3.6mA supply current. When the EN pin is then driven high (>1V), the chip is quickly switched to normal operating mode, avoiding the introduction of large charging time constants. Table 2 shows the logic of the EN pin and STBY pin. In both normal operating mode and standby mode, the maximum discharging current is about 300μA, and the maximum charging current is more than 4mA. In Figure 5 the simplified circuit schematic of the STBY (or EN) input is shown.

Table 2. The Logic of Different Operating Modes

EN	STBY	Comments
Low	Low	Shutdown Mode
Low	High	Standby Mode
High	Low or High	Normal Operation Mode

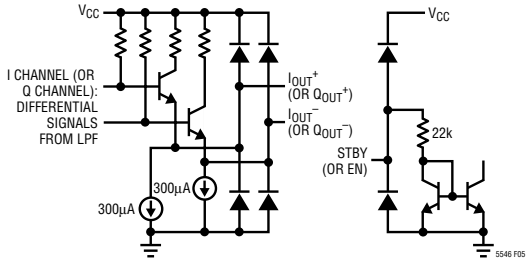


Figure 5. Simplified Circuit Schematic of I Channel (or Q Channel) Outputs and STBY (or EN) Input

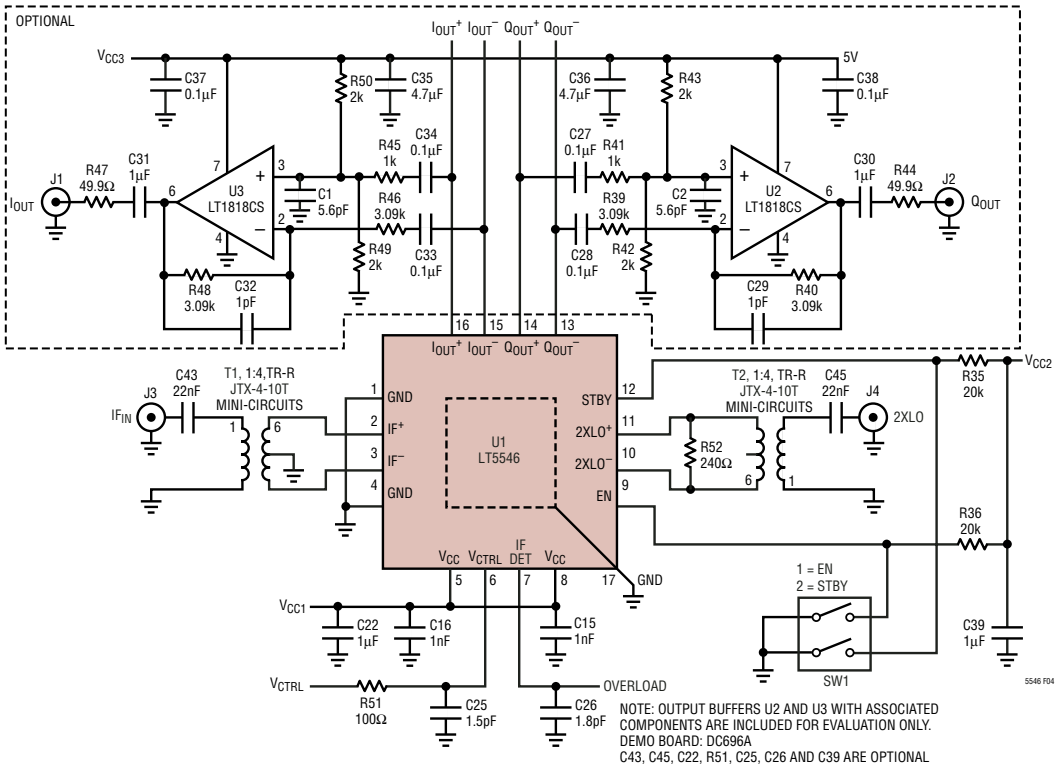


Figure 6. Evaluation Circuit Schematic with I/Q Output Buffers

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Evaluation Board

The evaluation circuit schematic is drawn in Figure 6. The components associated with buffers U2 and U3 are included to drive a 50Ω load for evaluation purposes only.

There is a unity voltage gain relationship for AC signals between the evaluation board outputs (I and Q) and the I_{OUT}^+, I_{OUT}^- or Q_{OUT}^+ and Q_{OUT}^- outputs of the LT5546 when the evaluation board outputs are terminated in 50Ω.

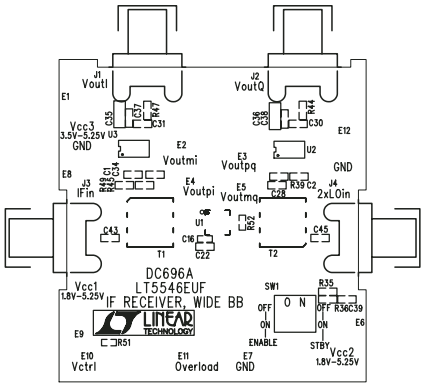


Figure 7. Component Side Silkscreen of Evaluation Board

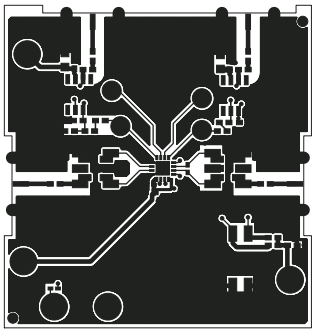


Figure 8. Component Side Layout of Evaluation Board

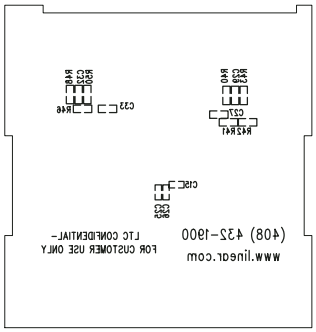


Figure 9. Bottom Side Silkscreen of Evaluation Board

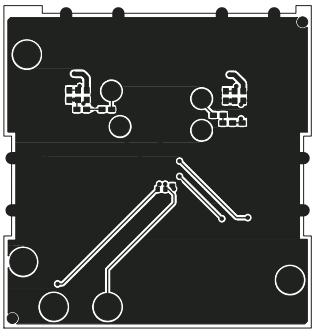


Figure 10. Bottom Side Layout of Evaluation Board

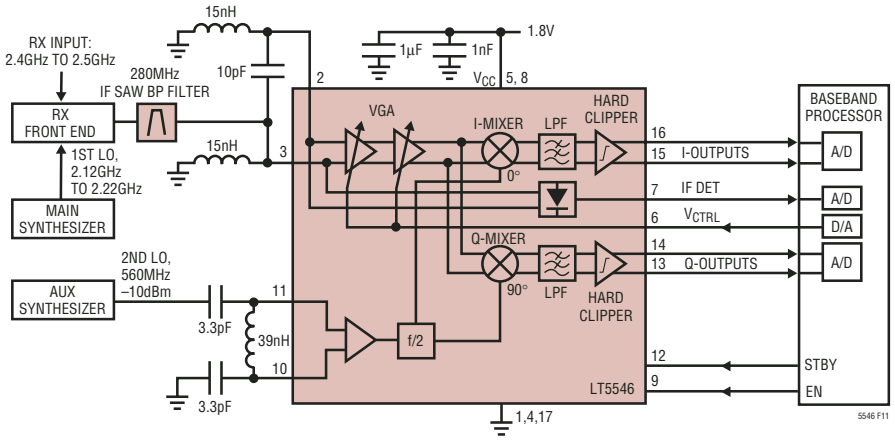
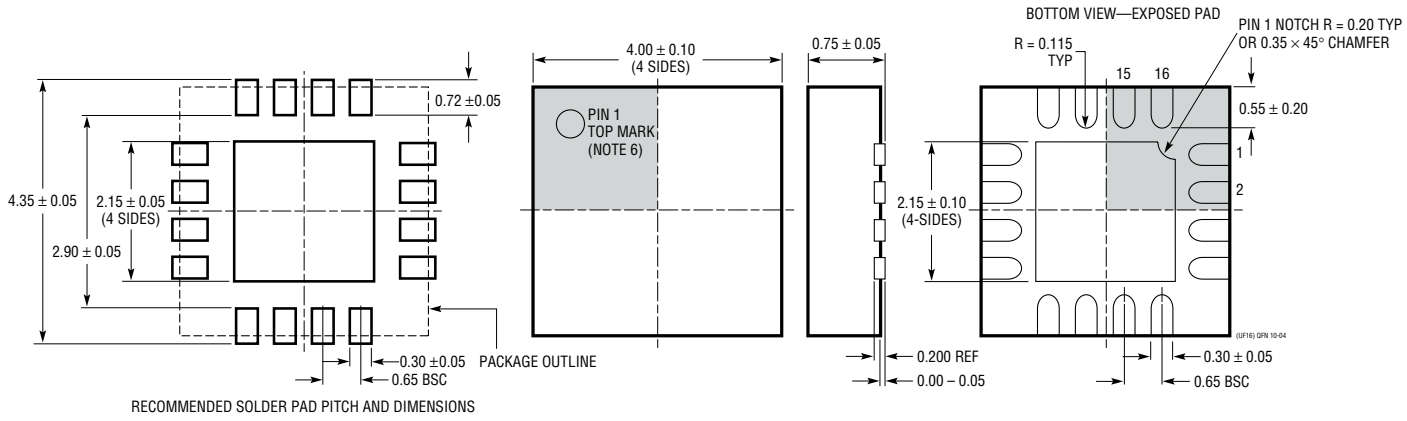


Figure 11. 2.4GHz to 2.5GHz Receiver Application (RX IF = 280MHz)

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PACKAGE DESCRIPTION

UF Package
16-Lead Plastic QFN (4mm × 4mm)
(Reference LTC DWG # 05-08-1692)



NOTE:
1. DRAWING CONFORMS TO JEDEC PACKAGE OUTLINE MO-220 VARIATION (WGGC)
2. DRAWING NOT TO SCALE
3. ALL DIMENSIONS ARE IN MILLIMETERS
4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE
5. EXPOSED PAD SHALL BE SOLDER PLATED
6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE TOP AND BOTTOM OF PACKAGE

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
Infrastructure		
LT5511	High Signal Level Upconverting Mixer	RF Output to 3GHz, 17dBm IIP3, Integrated LO Buffer
LT5512	High Signal Level Downconverting Mixer	DC-3GHz, 20dBm IIP3, Integrated LO Buffer
LT5515	1.5GHz to 2.5GHz Direct-Conversion Quadrature Demodulator	20dBm IIP3, NF =16.8dB, Integrated LO Quadrature Generator
LT5516	800MHz to 1.5GHz Direct-Conversion Quadrature Demodulator	4V to 5.25V Supply, 21.5dBm IIP3, NF = 12.8dB, Integrated LO Quadrature Generator
LT5522	600MHz to 2.7GHz High Signal Level Downconverting Mixer	4.5V to 5.25V Supply, 25dBm IIP3 at 900MHz, NF = 12.5dB, 50Ω Single-Ended RF and LO Ports
RF Power Detectors		
LT5504	800MHz to 2.7GHz RF Measuring Receiver	2.7V to 5.25V Supply, 80dB Dynamic Range, Temperature Compensated
LTC5505	RF Power Detectors with >40dB Dynamic Range	2.7V to 6V Supply, 300MHz to 3.5GHz, Temperature Compensated
LTC5507	100kHz to 1000MHz RF Power Detector	2.7V to 6V Supply, 48dB Dynamic Range, Temperature Compensated
LTC5508	0.3GHz to 7GHz RF Power Detector	2.7V to 6V Supply, 44dB Dynamic Range, Temperature Compensated
LTC5509	300MHz to 3GHz RF Power Detector	–30dBm to 6dBm, 600μA Supply Current, Temperature Compensated
LTC5532	300MHz to 7GHz Precision RF Power Detector	Precision V_{OUT} Offset Control, Adjustable Gain and Offset
RF Receiver Building Blocks		
LT5500	1.8GHz to 2.7GHz Receiver Front End	1.8V to 5.25V Supply, Dual-Gain LNA, Mixer
LT5502	400MHz Quadrature IF Demodulator with RSSI	1.8V to 5.25V Supply, 70MHz to 400MHz IF, 84dB Limiting Gain, 90dB RSSI Range
LT5503	1.2GHz to 2.7GHz Direct IQ Modulator and Mixer	1.8V to 5.25V Supply, Four Step RF Power Control, 120MHz Modulation Bandwidth
LT5506	40MHz to 500MHz Quadrature IF Demodulator with VGA	1.8V to 5.25V, I/Q Baseband Bandwidth 8.8MHz, –40dB to 57dB Linear Power Gain

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